

David FlÃ¡jtotto

List of Publications by Year in descending order

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Version: 2024-02-01

11
papers

226
citations

1307594

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1372567

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all docs

11
docs citations

11
times ranked

573
citing authors

#	ARTICLE	IF	CITATIONS
1	Observation of a smoothly tunable Dirac point in $\text{Ge}_2\text{Sb}_2\text{Te}_5$. Physical Review Materials, 2022, 6, .		
2	Massive Suppression of Proximity Pairing in Topological Bi_2Se_3 Films. Physical Review Letters, 2018, 120, 167201. $\mathbf{1}$	7.8	7
3	Gapped electronic structure of epitaxial stanene on InSb(111). Physical Review B, 2018, 97, .	3.2	91
4	Superconducting pairing of topological surface states in bismuth selenide films on niobium. Science Advances, 2018, 4, eaar7214.	10.3	36
5	In Situ Strain Tuning of the Dirac Surface States in Bi_2Se_3 Films. Nano Letters, 2018, 18, 5628-5632.	9.1	27
6	Experimental and theoretical electronic structure and symmetry effects in ultrathin NbSe ₂ films. Physical Review Materials, 2018, 2, .	2.4	11
7	Interdiffusion and stress development in single-crystalline Pd/Ag bilayers. Journal of Applied Physics, 2016, 119, 145308.	2.5	7
8	Interdiffusion in epitaxial, single-crystalline Au/Ag thin films studied by Auger electron spectroscopy sputter-depth profiling and positron annihilation. Acta Materialia, 2016, 107, 133-143.	7.9	14
9	Concentration-dependent self-diffusion coefficients in amorphous $\text{Si}_{1-x}\text{Ge}_x$ solid solutions: An interdiffusion study. Journal of Applied Physics, 2015, 117, 165306.	2.5	6
10	Single and multiple profile fitting of AES and XPS intensityâ€depth profiles for analysis of interdiffusion in thin films. Surface and Interface Analysis, 2014, 46, 1057-1063.	1.8	9
11	Quantum Confinement Drives Macroscopic Stress Oscillations at the Initial Stage of Thin Film Growth. Physical Review Letters, 2012, 109, 045501.	7.8	18